

80 V, 1 A PNP medium power transistors Rev. 2 — 29 April 2019

**Product data sheet** 

# 1. Product profile

### 1.1. General description

PNP medium power transistors in a medium power SOT223 (SC73) Surface-Mounted Device (SMD) plastic package.

#### Table 1. Product overview

Type number	Package		NPN comlement	
	Nexperia	JEDEC		
BCP53T	SOT223	SC-73	BCP56T	
BCP53-10T			BCP56-10T	
BCP53-16T	-		BCP56-16T	

### 1.2. Features and benefits

- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- Three current gain selections
- High power dissipation capability
- AEC-Q101 qualified

### 1.3. Applications

- Linear voltage regulators
- MOSFET drivers
- High-side switches
- Power management
- Amplifiers

### 1.4. Quick reference data

#### Table 2. Quick reference data

#### $T_{amb}$ = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-80	V
I <sub>C</sub>	collector current		-	-	-1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-2	A

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
h <sub>FE</sub>	DC current gain						_
B	BCP53T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	250	
	BCP53-10T		[1]	63	-	160	
	BCP53-16T	_	[1]	100	-	250	

[1] pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

### 2. Pinning information

Table 3. Pinning				
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	ç
2	С	collector		B
3	E	emitter		
4	С	collector	<b>∃</b> 1 <b>∃</b> 2 <b>∃</b> 3	E sym132

# 3. Ordering information

Table 4. Ordering	g information	1					
Type number	Package	Package					
	Name	Description	Version				
BCP53T	SC-73	plastic, surface-mounted package with increased heatsink;	SOT223				
BCP53-10T		4 leads					
BCP53-16T							

### 4. Marking

Table 5. Marking				
Type number	Marking code			
BCP53T	BCP53T			
BCP53-10T	P5310T			
BCP53-16T	P5316T			

### 5. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	open emitter		-100	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-80	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-1	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-2	А
I <sub>B</sub>	base current			-	-0.2	А
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-0.3	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1	W
			[3]	-	1.3	W
			[4]	-	1.3	W
			[5]	-	1.8	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

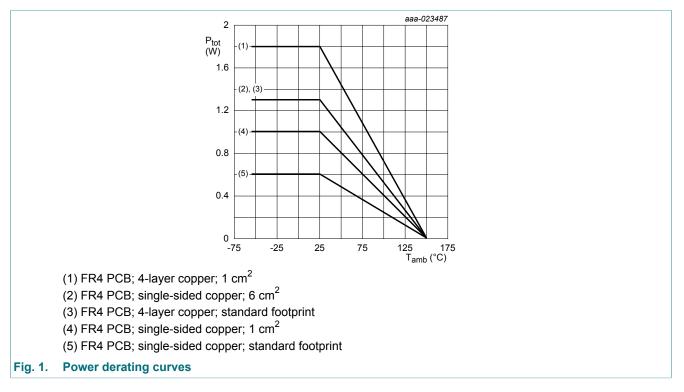
[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

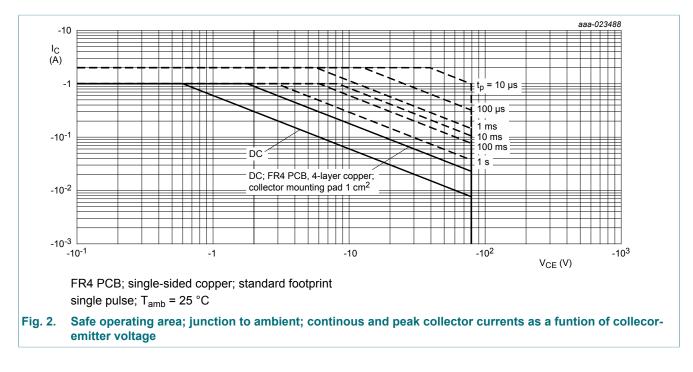
[3] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.

[5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm.<sup>2</sup>



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### 6. Thermal characteristics

#### **Table 7. Thermal characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	209	K/W
		[2]			125	K/W	
			[3]			97	K/W
			[4]	-	-	97	K/W
			[5]	-	-	70	K/W
R <sub>(j-sp)</sub>	thermal resistance from junction to solder point			-	-	18	K/W

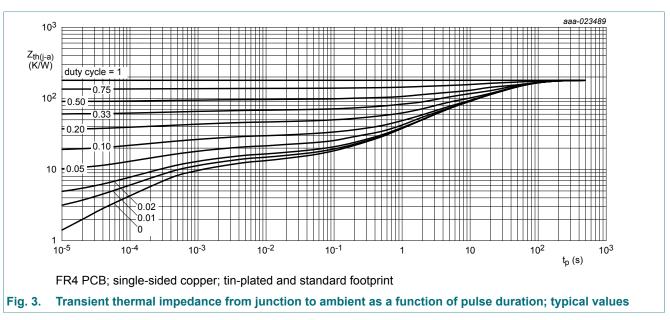
Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint. [1]

Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [2]

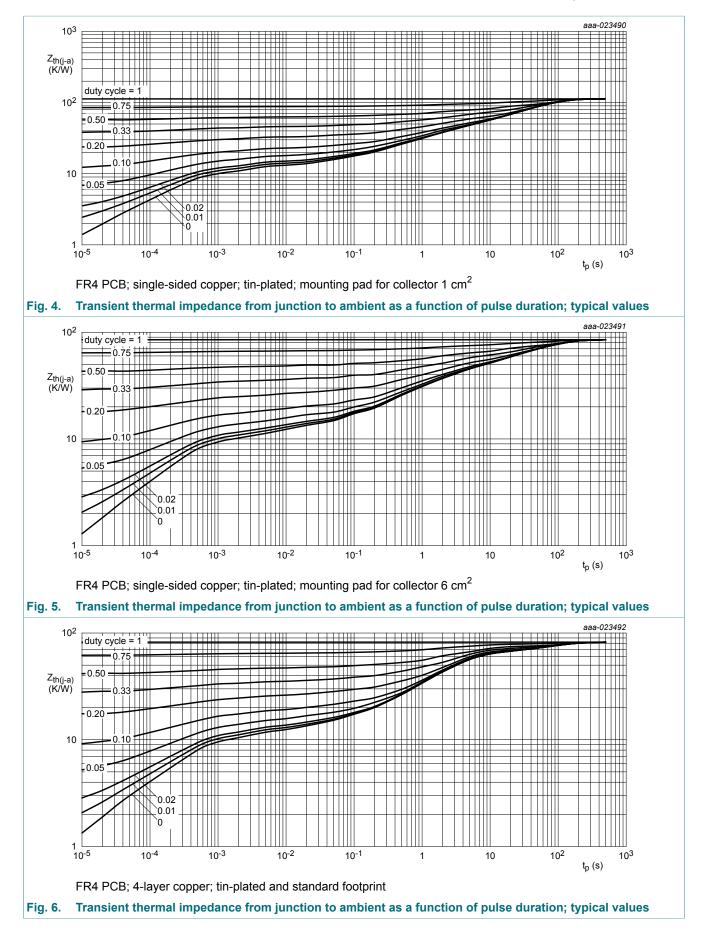
[3]

Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint. [4]

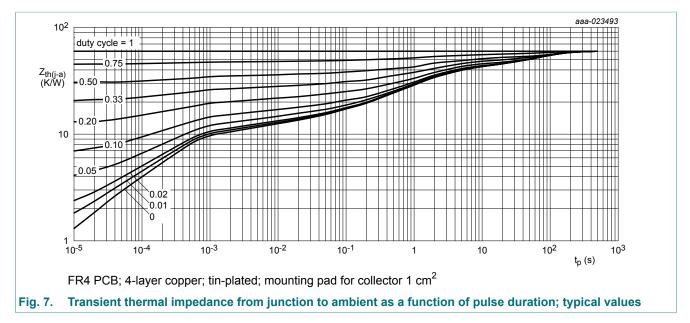
[5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm<sup>2</sup>.



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### 7. Characteristics

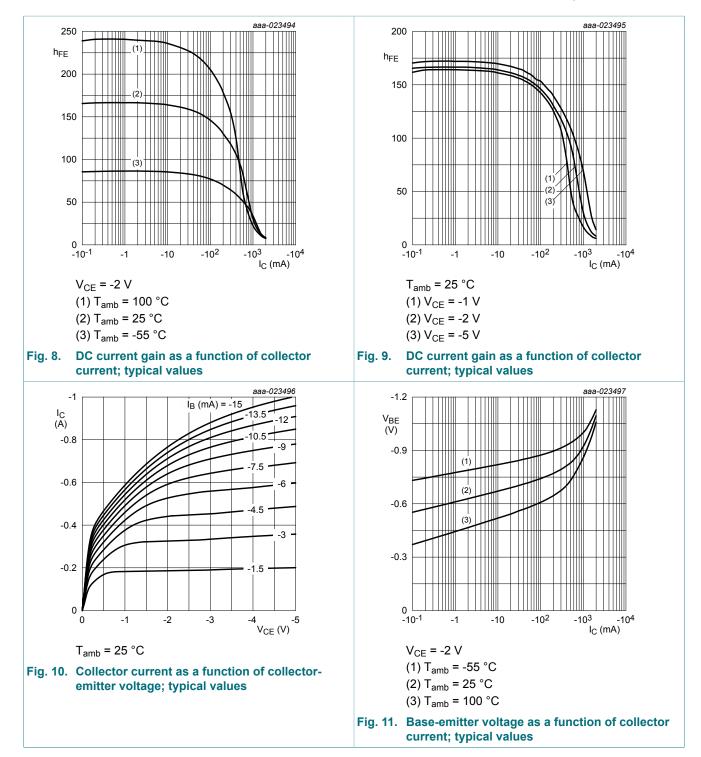
#### **Table 8. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

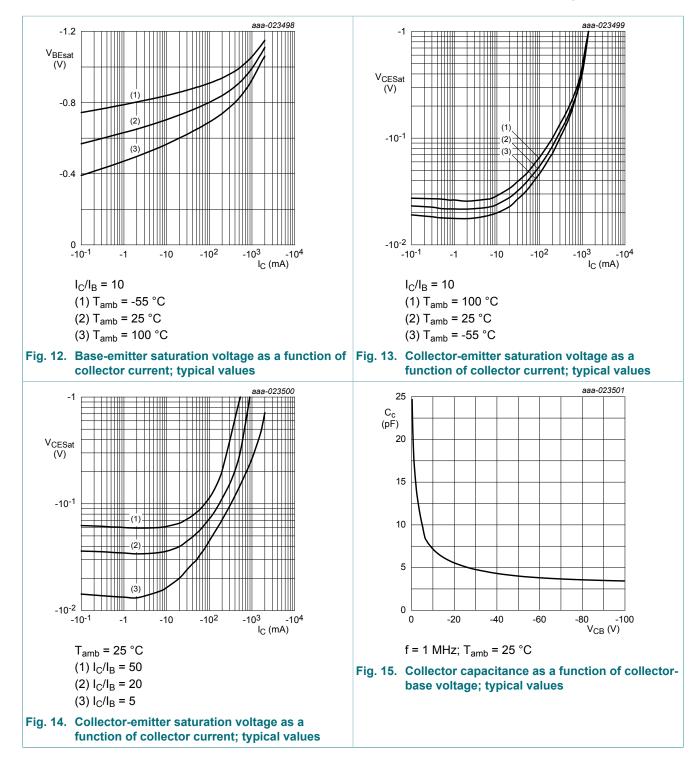
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = -100 μA; I <sub>E</sub> = 0 A		-100	-		V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = -2 mA; I <sub>E</sub> = 0 A		-80	-		V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>E</sub> = -100 μA; I <sub>C</sub> = 0 A		-5	-		V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A		-	-	-100	nA
	cut-off current	V <sub>CB</sub> = -30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-10	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	-100	nA
h <sub>FE</sub> DC current gain			1				
BCP53T, -10T, -16T	BCP53T, -10T, -16T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -5 mA		63	-	-	
		V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA	[1]	40	-	-	
	BCP53T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	250	
	BCP53-10T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	63	-	160	
	BCP53-16T	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -150 mA	[1]	100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = -500 mA; I <sub>B</sub> = -50 mA	[1]	-	-	-500	mV
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = -2 V; I <sub>C</sub> = -500 mA	[1]	-	-	-1	V
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -50 mA; f = 100 MHz		100	140	-	MHz
Cc	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz		-	7	-	pF

[1] pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

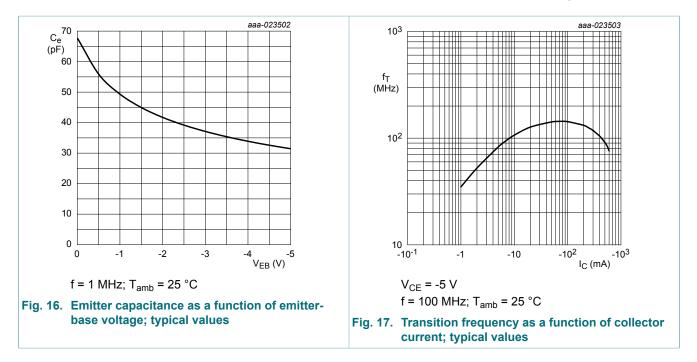
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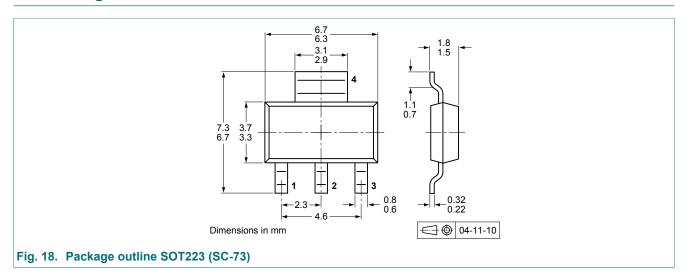


### 8. Test information

### 8.1. Quality information

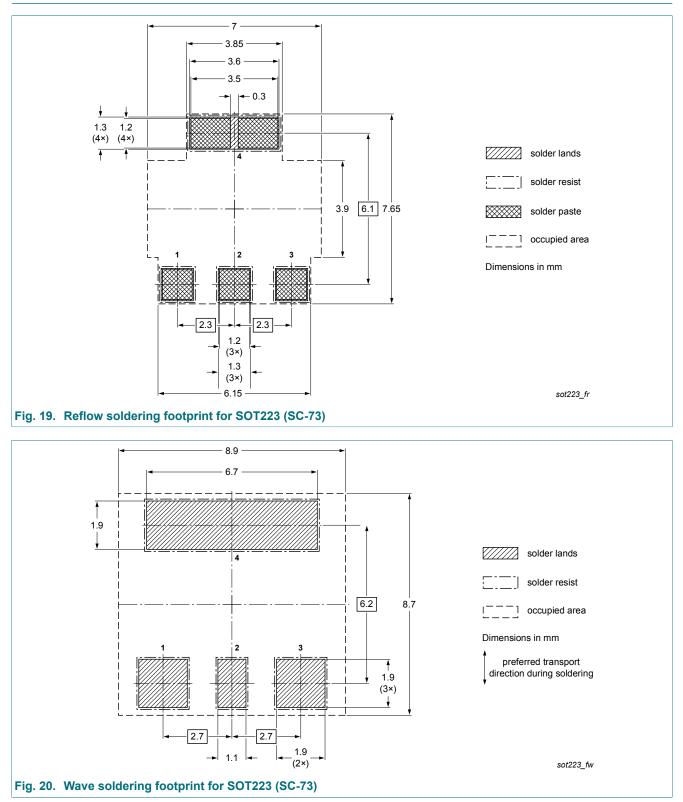
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### 9. Package outline



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# 10. Soldering



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# **11. Revision history**

Table 9. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCP53T_SER v.2	20190429	Product data sheet	-	BCP53T_SER v.1		
Modifications:	<ul> <li>Characteristics: breakdown voltages added</li> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
BCP53T_SER v.1	20160705	Product data sheet	-	-		

# 12. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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